A REVIEW OF LOW POWER FLASH ADC USING THRESHOLD INVERTER QUANTIZATION TECHNIQUE

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ABSTRACT
Digital signal processing algorithms were becoming increasingly more powerful while advances in integrated circuit technology provided compact, efficient implementation of these algorithms in silicon. In the design of mixed-signal and system on chip (SOC) applications the analog-to-digital converter (ADC), is a key functional block which limits the performance and the speed of the system. The analog-to-digital converter is one of the most important component of signal processing and communication systems. An Analog to digital converter is a circuit that converts an analog signal such as a sound picked up by a microphone or light entering a digital camera, into digital signal. There are different types of ADCs depending on type of applications. There are three main categories of ADCs depending on the speed of operation i.e. low speed serial ADC, medium speed ADC and high speed ADC. The different types of ADCs based on various topologies are: Flash ADC, Sigma delta ADC, Ramp counter ADC, Successive approximation ADC. The flash ADC is known for having the fastest speed compared to other ADC architectures. Therefore, it is used for high-speed and very large bandwidth applications such as radar processing, digital oscilloscopes, high-density disk drives, and so on. This paper presents review of Low Power Flash ADC using Threshold inverter quantization technique.
KEYWORDS: Analog-to-digital converter, Flash ADC, Threshold Inverter Quantization, Comparator, Resolution, Low Power, Encoder.

INTRODUCTION
Naturally occurring signals are analog in nature which are at least at a macroscopic level i.e. these signals are continuous and can take infinity of values. As we know in digital domain the operation and functionality of signals become more accurate and faster than the analog domain. So there must be a circuit needed that converts the naturally analog signals into digital this circuit is known as Analog to Digital Converter. An Analog to Digital circuit converts continuous amplitude and continuous time signals into discrete amplitude and discrete time signals. Digital to Analog Converter is required whenever analog signal is needed back.

FLASH ADC
Among various known high speed ADC architectures two most common implementations are the Flash type and the Pipeline architecture. The Flash ADC is faster of two but limited to lower resolution due to a large no. of components \((2^n-1\) comparators for \(n\)-bit ADC). The Pipeline ADC architecture is slower of two but is more suitable for higher resolution (require \(n\)-stages for \(n\)-bit ADC). The Flash ADC is the Fastest ADC among all the ADC architectures available because of its parallel comparator array that facilitates parallel data conversion. A Flash ADC comprises of comprises of two blocks: comparator and encoder. Comparator block compares the input signal with the reference signal and generate thermocode and the Encoder block converts the thermocodes into digital outputs.

Fig 1: Block Diagram of the TIQ Flash ADC.
LITERATURE REVIEW

This paper describes low power Flash ADC using Threshold inverter quantization technique with different resolution, supply voltage, and different CMOS technologies.

[01]. “Design of Low Power 0.8v Flash ADC using TIQ in 90nm Technology” Ranam Sireesha and Abhishek Kumar; introduced a 04-bit low power Flash analog-to-digital converter using Threshold inverter quantization (TIQ) comparator that is this circuit does not require resister ladder that leads to area and power saving. This design operated at 800mv, input frequency of 1KHZ with reduced power consumption of 14.08 µw and 200usec delay. The main purpose of this architecture (i.e. TIQ comparator and a low power high efficient encoder) is to reduce power. This design is simulated using cadence spectre 90nm technology.

[02]. “Design of a TIQ Comparator For High Speed And Low Power 04-Bit Flash ADC” Sujeet Mishra and Balchand Nagar; define that the major building block for improvement of power and speed specification is comparator. They introduces a new design for comparator with Threshold Inverter Quantization for Flash ADC, that requires 2^n-1 comparators for generation of thermocode. The proposed design provides high speed, low power, and smaller area with different P-mos and N-mos widths and power supply of 0.99v. The design is simulated using Tanner tool 0.25um CMOS technology.

[03]. “A Novel Approach to 03-bit Flash ADC” Kalpana Chaudhary and R.B. Singh; proposed that use the digital inverters as analog voltage comparators. This eliminates the requirement of high gain differential input voltage comparators that are inherently more compound and slower than digital inverters. This 03-bit Flash ADC is implemented on 90nm process technology in standard CMOS digital design and simulations are done using Tanner EDA tool with supply 0.9v. This design is highly suitable for the complete SOC integration using the standard CMOS digital process.

[04]. “A 4 GS/s, 1.8v multiplexer encoder based Flash ADC using TIQ technique” Liyaqat nazir, Roohie Naaz Mir and Najeeb-ud-din Hakim; describes the ultra high speed ADC using a 2*1 multiplexer based encoder i.e. highly suitable and accurate. This ADC is designed with 04-bit resolution, 1.8v supply and a steep size of 0.038125v. The analog part of this ADC is fully pipelined, providing sampling rate 2GS/s consumed 42mw power. The input frequency for this ADC is 1GHZ which results DNL of less than 0.5LSB and INL less than 0.7LSB.
The complete ADC consumes less than 145uw with speed 4GS/s. The proposed TIQ flash ADC has been designed with standard CMOS technology parameters keeping length of channel equal to 0.12µm with 1.8v supply. The simulation is done using HSPICE model (BSIM3).

[05]. “Design method and automation of comparator generation for flash A/D converter” Daegyu Lee, Jinchoeol yoo, Kyusum Choi; present the design methods and the automation of the comparator circuit layout generation for Flash ADC. The TIQ based ADC require 2^n-1 comparator each are different from all others. The authors present an optimal design method of the CMOS TIQ comparators and their automatic layout generation that significantly improves the linearity of the ADC against the CMOS process variation can be almost eliminated. The resulting Flash ADC features higher speed, lower power consumption, smaller size and more readiness for the SOC integration.

[06]. “A 1-GSPS CMOS Flash A/D Converter for System-on-Chip Applications” Jinchoeol yoo, Kyusum Choi, Ali Tangel; introduce an ultrafast CMOS ADC design that uses TIQ technique for comparator. TIQ is used for high speed. In this paper authors designed a 6-bit TIQ based Flash ADC with 0.25µm standard CMOS technology parameter and it operates with sampling rate upto 1GSPS and power dissipation is 66.87mw at 2.5v and occupies 0.13mm² area. The proposed ADC is suitable for system-on-chip in wireless products and other ultra high speed applications. Here the device designed with 63 comparators and 63 gain boosters and an encoder.

[07]. “Low-power self reconfigurable multiplexer based decoder for Adaptive resolution Flash ADCs” Chetan Vudadha, Goutham Makkena, M Venkata Swamy Nayudu, Sai Phaneendra P, Syed Eeshad Ahmed, Sreehari Veeramachaneni, N Mooorthy Muthukrishnan, M.B. Srinivass; present a new improved 2:1 multiplexer based decoder for flash ADCs. The proposed decoder can be configured to operate on thermometer code with reduced length without any extra overhead. All the architectures were structurally described using Verilog HDL and simulated using cadence incive unified simulator (IUS) v6.1 covering all functional combinations. The designs were mapped on the TSMC 180nm technology with slow normal library (operating conditions 1.8v, 125°C) using cadence RTL compiler v7.1. The power analysis is done on all designs with 50% toggle rate at 500MHZ frequency.
“Design of a 1.5v, 4-bit Flash ADC using 90nm Technology” Arunkumar. P. Chavan, Rekha, G.P. Narashimaraja; introduce a 4-bit analog to digital converter is designed for low power CMOS, which requires 2^n-1 comparators, an encoder to convert thermometer code to binary code. This circuit uses a preamplifier and a latch stage. The preamplifier stage to achieve an acceptable gain, and the latch stage consists of two inverters which are connected in a back to back fashion forming a differential comparator and an nmos transistor is connected between the differential nodes of the latch. The circuit operates with an input frequency of 25 MHZ and 1.5v supply with a conversion time of 6.182ns. The design is simulated using cadence environment with 90nm technology, which shows a low power dissipation of 1.984mw for the designed ADC.

“Simulation and Analysis of 2:1 Multiplexer Circuits at 90nm Technology” Ila Gupta, Neha Arora, Prof. B.P. Singh; describe that a multiplexer is a unidirectional device that used in application in which data must be switched from multiple sources to a destination. This paper represents the simulation of different 2*1 multiplexer configurations and their comparative analysis on different parameters such as power supply, voltage, operating frequency, temperature, load capacitance and area efficiency etc. All the simulation have been carried out on BSIM 3V3 90nm technology at Tanner EDA tool. Now a days low power become important consideration as performance and area. This paper consists literature review of different 2*1 multiplexer circuits as; NMOS multiplexer circuit, CMOS multiplexer circuit, Multiplexer single with level restoration (MSL) multiplexer circuit, Multiplexer double (MD) multiplexer circuit, Differential cascade voltage switch logic (DCVSL) multiplexer circuit, Modified differential cascade voltage switch logic (MDCVSL) multiplexer circuit. This paper concluded with the efficient approach of multiplexer. NMOS circuit is showing better result over operating frequency up to the range 200MHZ. MDCVSL circuit shows the least power delay product over a range of supply voltages.

“Study and implementation of comparator in CMOS 50nm technology” Dharmendra B. Mavani, Arun B. Nandurbarkar; describe the comparator circuits used in Flash ADC. In this paper TIQ and Two stage open loop comparator design styles are described. Two stage open loop comparator is implemented in 50nm CMOS technology. Pre-simulation of comparator is done in LT-Spice and post layout simulation is done in microwind 3.1. Comparator is the “Heart” of the ADC. The inverter threshold is defined as the V_{in}=V_{out} in the VTC of an inverter. The second inverter is used to increase voltage gain and to present an unbalanced
propagation delay. The two stage open loop comparator has two differential inputs. The
advantage of this circuit is that the circuit consumes minimal number of transistors and thus
the circuit area is small. Two stage open loop comparator is presented using 50nm CMOS
technology.

[11]. “Design of 3-bit low power flash type ADC” Sarojini Mandal, Dr. J.K. Das; define that
Simple two stage op-amp with miller capacitance can be used as a high gain comparator. It is
simulated in 180nm technology using Cadance Virtuso analog design environment
simulation. The op-amp uses a 1.8v $V_{dd}$ and a 1.8v $V_{ss}$ and consumes power of around
0.9mw. The analog output of each comparator is encoded using cascading full adder designed
by transistor logic that makes the circuit more faster. This paper introduces a low power op-
amp modified from the traditional one and an encoder employing cascaded full adders with
pass transistor logic gates. A current mirror is used as a biasing circuit that is free from
voltage sources and utilize current as a reference source. A miller compensation capacitor is
used to maintain the stability of the circuit and increase phase margin.

[12]. “Study of a 3-bit CMOS flash ADC utilizing Threshold Inverter Quantization
technique” Kalpana Chaudhary, R.B. Singh; describe a 3-bit ADC which is most essential
part of a system-on-chip device as it minimizes the gap between analog and digital world.
The proposed ADC utilizes TIQ technique that uses two cascaded CMOS inverters as a
comparator. The TIQ technique proposed here for better implementation in SOC applications
using Flash ADC. With the advancement in technology, digital signal processing has gained
significant importance in the field of telecommunication, biomedical, control system and so
on. Flash ADC is high speed and low resolution device, its high speed is due to of its parallel
architecture, all conversions are done in one cycle with many comparators. The name of TIQ
technique is based on the logic of using two cascading inverters as voltage comparators. By
using these technique there is no need of voltage comparator and no need of resistor ladder
circuit used in conventional Flash ADC. The implementation is carried out on Tanner EDA
tool 90nm process technology. The TIQ Flash ADC provides higher data sampling rate and
operates at low voltage and also low power consumption.

present the design of an 8-bit Flash ADC with TIQ comparators,. Speed of this ADC is
787.78mbps and the power consumed is 800mw. In this design the comparators are realized
with the inverters, which avoids the complexity in the design of conventional comparators.
The TIQ comparator consists of two cascaded CMOS inverters. The analog input signal quantization level is set in the first stage by changing the VTC by means of transistor sizing. The second inverter stage is used for increased gain and logic level inversion so that the circuit behaves as an internally set comparator circuit. The key point about second stage is that it must be exactly same as the first stage to maintain the same DC threshold levels and to keep the linearity in balance for the voltage rising and falling intervals of high frequency input signals.

[14]. “Employing threshold inverter quantization (TIQ) technique in designing 9-bit folding and interpolation CMOS analog-to-digital converters (ADC)” Oktay Aytar and Ali Tangel; This paper present designing and interpolation of a 9-bit folding and interpolation ADC using 0.35 µm CMOS C35B4 model under AMS-HIT kit library. The complete system consist of two main blocks, one of them is 4-bit flash ADC using TIQ technique and second one is the 5-bit fine ADC part of the converter. The designed converter works with 5v power supply and has analog input range of 34 VPP. Analog input bandwidth is 1MHZ with clock frequency of 2GHZ for the digital part. The linearity measures of the converter include 2.9LSB of DNL and 6.3 LSB of INL. The main purpose of this paper work is to investigate the possibility of employing TIQ technique in designing folding and interpolation types ADCs. Although the linearity measures are not satisfying for 9-bit case. The reduction of comparator count is obtained by analogue pre-processing circuits. The designed converter was also fabricated through Europractice.

[15]. “A Power Efficient 6-Bit TIQ ADC Designed for Portable Applications” Satya Narayan Mishra, Wasim Arif, Jishan megedi, Srimanta Baishya; present a power efficient ADC is an important module for long lifespan of battery for the portable applications. The high speed and low power ADC design is achieved by using TIQ comparator instead of traditional high gain differential comparator and the Decoder is designed using multiplexer instead of traditional ROM decoder. The proposed model simulated with UMC 180nm CMOS technology in CADENCE VERTUOSO platform and the result of this shows that the proposed model achieves high speed, low power consumption, low voltage operation compared to other conventional ADCs. ADC acts as interface between real world signals and electronic world because most of the natural occurring signals are analog in nature and most of the systems are digital in nature. This paper contains 6-bit ADC designed using TIQ concept in UMC 180nm CMOS technology. Here the modified multiplexer based decoder is
used to increase speed by reducing fan-out in critical path of decoder. The designed ADC works on only 1.23mw of power acceptable linearity error.

CONCLUSION
A simple and fast A/D converter architecture that uses inverter comparator for Flash A/D conversion, named TIQ technique, has been proposed. The TIQ based ADC circuits offer higher data conversion rates while maintain a comparable power consumption level. This paper gives information about the Flash ADC using TIQ technique defined by different researchers with different parameters.

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BIOGRAPHY

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